Nihon Inter Electronics Corporation

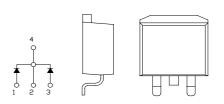
$\textbf{SBD} \quad \texttt{Type} : C20T04QH$

OUTLINE DRAWING

FEATURES

*SQUARE-PAK TO-263AB(SMD)
Packaged in 24mm Tape and Reel

- *Dual Diodes Cathode Common
- *Low Forward Voltage Drop
- *High Surge Capability
- *Tj=150 °C operation



Maximum Ratings

Approx Net Weight: 1.4g

Rating	Symbol	C20T04QH			Unit
Repetitive Peak Reverse Voltage	V_{RRM}	40			V
Repetitive Peak Surge Reverse Voltage	Vrrsm	45(pulse width $\leq 1\mu s$ duty $\leq 1/50$)		V	
Average Rectified Output Current	I_{O}	20	Tc=127°C	50 Hz Full Sine Wave Resistive Load	A
RMS Forward Current	I _{F(RMS)}	22.2		Α	
Surge Forward Current	I _{FSM}	180	50Hz Full Sine Wave ,1cycle Non-repetitive		Α
Operating JunctionTemperature Range	T_{jw}	-40 to +150		°C	
Storage Temperature Range	Tstg	-40 to +150		°C	

Electrical • Thermal Characteristics

Characteristics	Symbol	Conditions	Min.	Тур.	Max.	Unit
Peak Reverse Current	I_{RM}	Tj= 25°C, V _{RM} = V _{RRM} per arm	-	-	1	mA
Peak Forward Voltage	V_{FM}	Tj= 25°C, I _{FM} = 10 A per arm	-	-	0.61	V
Thermal Resistance	Rth ₍ j-c)	Junction to Case	ı	ı	1.5	°C/W

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C20T04QH OUTLINE DRAWING (Dimentions in mm)

